Schottky Barrier Diode

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 150°C unless otherwise noted)

Rating	Symbol	Value	Unit
Forward Current	١ _F	70	mA
Non–Repetitive Peak Forward Surge Current (t ≤ 1.0 s)	I _{FSM}	100	mA
Reverse Voltage	V _R	70	V

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	225 1.8	mW mW/°C
Thermal Resistance – Junction-to-Ambient (Note 1) (Note 2)	$R_{ hetaJA}$	508 311	°C/W
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 @ minimum pad.

2. FR-4 @ 1.0 x 1.0 in pad.



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70 VOLTS SCHOTTKY BARRIER DIODE



Device	Package	Shipping [†]
BAS70-04LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SBAS70-04LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Мах	Unit
Reverse Breakdown Voltage (I _R = 10 μA)	V _{(BR)R}	70	_	V
Total Capacitance (V _R = 0 V, f = 1.0 MHz)	CT	_	2.0	pF
Reverse Leakage (V _R = 50 V) (V _R = 70 V)	I _R		0.1 10	μΑ
Forward Voltage $(I_F = 1.0 \text{ mA})$ $(I_F = 10 \text{ mA})$ $(I_F = 15 \text{ mA})$	V _F	- - -	410 750 1000	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



TYPICAL CHARACTERISTICS



Figure 3. Typical Capacitance





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